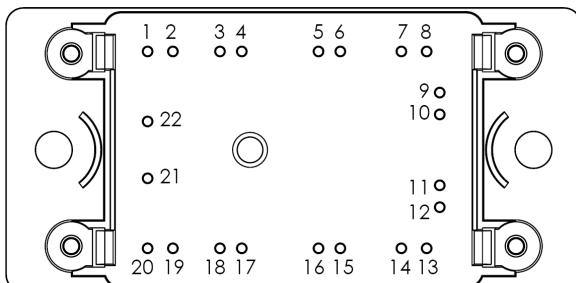
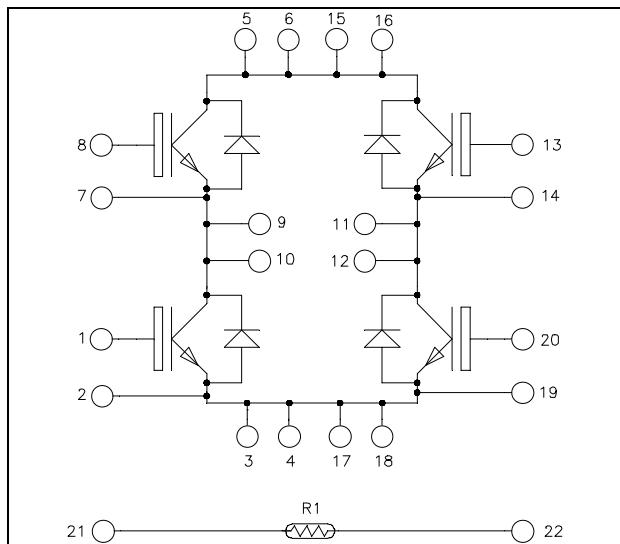


**Full - Bridge
NPT IGBT Power Module**
 $V_{CES} = 1200V$
 $I_C = 25A @ T_c = 80^\circ C$


Pins 5/6/15/16 ; 3/4/17/18 ; 9/10 ; 11/12 must be shorted together

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Fieldstop IGBT
 - Low voltage drop
 - short tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Very low stray inductance
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

Absolute maximum ratings (per IGBT)

Symbol	Parameter	Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage	1200	V
I_C	Continuous Collector Current	$T_c = 25^\circ C$	A
		$T_c = 80^\circ C$	
I_{CM}	Pulsed Collector Current	$T_c = 25^\circ C$	50
V_{GE}	Gate – Emitter Voltage	± 20	V
P_D	Maximum Power Dissipation	$T_c = 25^\circ C$	227
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^\circ C$	50A@1150V

 **CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

Electrical Characteristics (per IGBT)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I _{CES}	Zero Gate Voltage Collector Current	V _{GE} = 0V ; V _{CE} = 1200V				250	µA
V _{CE(sat)}	Collector Emitter saturation Voltage	V _{GE} = 15V	T _j = 25°C		2.1		V
		I _C = 25A	T _j = 125°C		2.3		
V _{GE(th)}	Gate Threshold Voltage	V _{GE} = V _{CE} , I _C = 1mA		3	5.5	7	V
I _{GES}	Gate – Emitter Leakage Current	V _{GE} = 20V, V _{CE} = 0V				150	nA

Dynamic Characteristics (per IGBT)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
C _{ies}	Input Capacitance	V _{GE} = 0V V _{CE} = 25V f = 1MHz		2.02			nF
C _{oes}	Output Capacitance			0.19			
C _{res}	Reverse Transfer Capacitance			0.06			
Q _G	Gate charge	V _{GE} = 8/20V, I _C = 25A V _{CE} = 600V			280		nC
T _{d(on)}	Turn-on Delay Time	Inductive Switching (125°C) V _{GE} = 15V V _{Bus} = 600V I _C = 25A R _G = 16Ω		60			ns
T _r	Rise Time		50				
T _{d(off)}	Turn-off Delay Time		346				
T _f	Fall Time		40				
E _{on}	Turn-on Switching Energy	V _{GE} = 15V V _{Bus} = 600V I _C = 25A R _G = 16Ω	T _j = 125°C		1.35		mJ
E _{off}	Turn-off Switching Energy		T _j = 125°C		1.76		
I _{sc}	Short Circuit data	V _{GE} ≤ 15V ; V _{Bus} = 900V t _p ≤ 10µs ; T _j = 125°C			125		A
R _{thJC}	Junction to Case Thermal Resistance					0.55	°C/W

Reverse diode ratings and characteristics (per diode)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit	
V _{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V	
I _{RM}	Maximum Reverse Leakage Current	V _R =1200V				100	µA	
I _F	DC Forward Current			T _c = 80°C	25		A	
V _F	Diode Forward Voltage	I _F = 25A			2.6	3.1	V	
		I _F = 50A			3.2			
		I _F = 25A	T _j = 125°C		1.8			
t _{rr}	Reverse Recovery Time	I _F = 25A V _R = 667V di/dt = 200A/µs	T _j = 25°C		320		ns	
			T _j = 125°C		360			
Q _{rr}	Reverse Recovery Charge		T _j = 25°C		480		nC	
			T _j = 125°C		1800			
R _{thJC}	Junction to Case Thermal Resistance					1.4	°C/W	

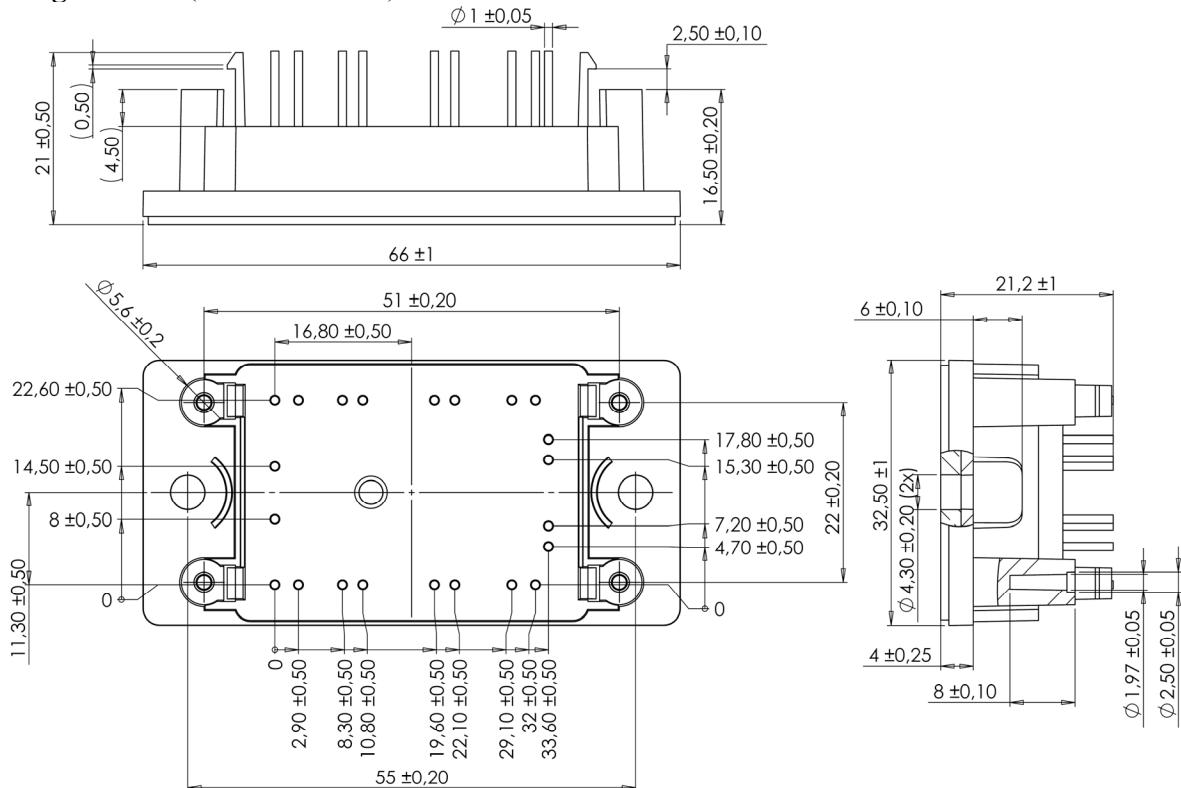
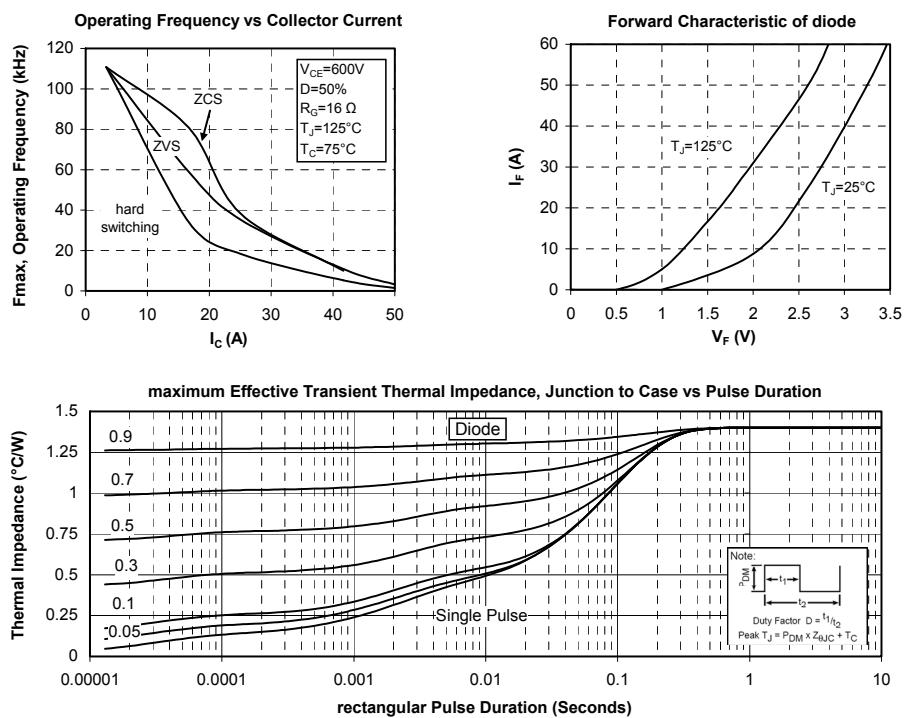
Temperature sensor NTC

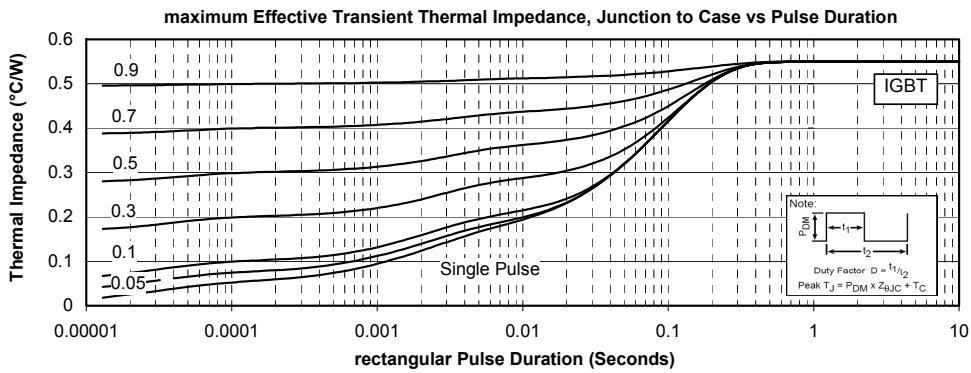
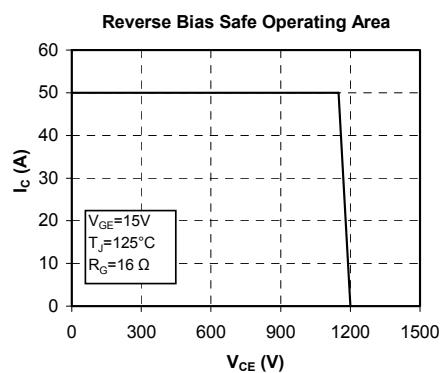
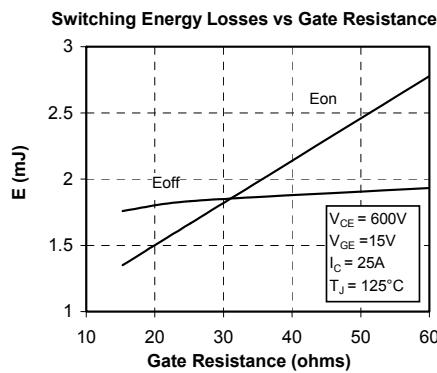
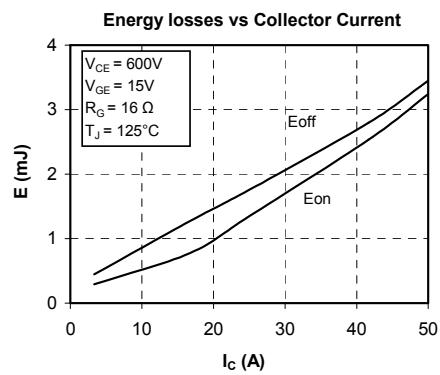
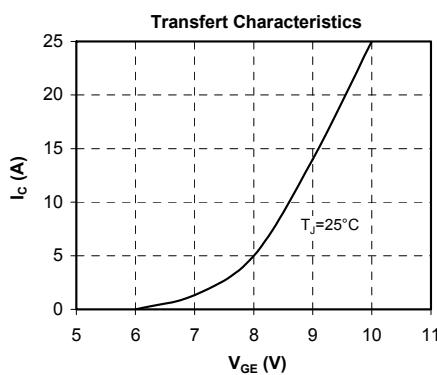
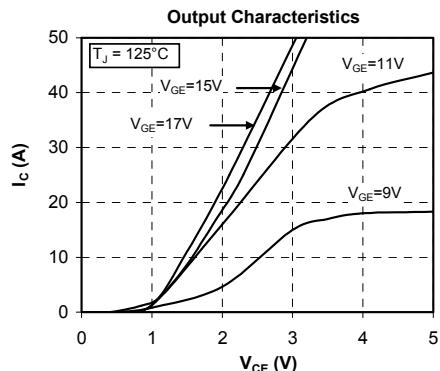
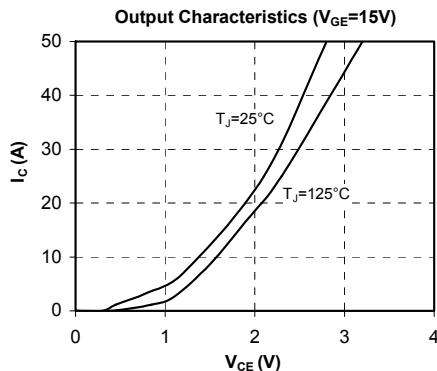
Symbol	Characteristic	Min	Typ	Max	Unit
R ₂₅	Resistance @ 25°C		22		kΩ
ΔR ₂₅ /R ₂₅	Resistance tolerance			5	%
ΔB/B	Beta tolerance			3	
B _{25/100}	T ₂₅ = 298.16 K		3980		K

$$R_T = \frac{R_{25}}{\exp\left[B_{25/100}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$
 T: Thermistor temperature
 R_T: Thermistor value at T

Thermal and package characteristics

Symbol	Characteristic	Min	Typ	Max	Unit	
V _{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz	4000			V	
T _j	Operating junction temperature range	-40		150	°C	
T _{STG}	Storage Temperature Range	-40		125		
T _C	Operating Case Temperature	-40		100		
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package Weight				75	g

Package outline (dimensions in mm)

Typical Performance Curve




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